

HD74HCT244

Octal Buffers/Line Drivers/Line Receivers (with inverted 3-state outputs)

REJ03D0664-0200 (Previous ADE-205-553) Rev.2.00 Mar 30, 2006

Description

The HD74HCT244 is a non-inverting buffer and has two active low enable ($1\overline{G}$ and $2\overline{G}$). Each enable independently controls 4 buffers.

This device does not have schmitt trigger inputs.

Features

• LSTTL Output Logic Level Compatibility as well as CMOS Output Compatibility

• High Speed Operation: t_{pd} (A to Y) = 10 ns typ ($C_L = 50 \text{ pF}$)

• High Output Current: Fanout of 15 LSTTL Loads

• Wide Operating Voltage: $V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$

• Low Input Current: 1 µA max

• Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max (Ta = 25°C)

• Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HCT244P	DILP-20 pin	PRDP0020AC-B (DP-20NEV)	Р	_
HD74HCT244FPEL	SOP-20 pin (JEITA)	PRSP0020DD-B (FP-20DAV)	FP	EL (2,000 pcs/reel)
HD74HCT244RPEL	SOP-20 pin (JEDEC)	PRSP0020DC-A (FP-20DBV)	RP	EL (1,000 pcs/reel)
HD74HCT244TELL	TSSOP-20 pin	PTSP0020JB-A (TTP-20DAV)	Т	ELL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

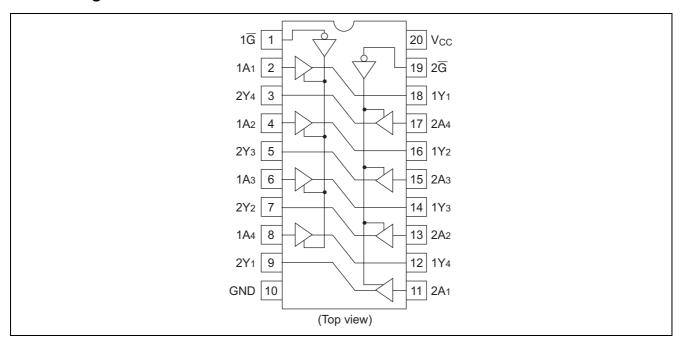
Function Table

Inp	Output	
G	Α	Υ
Н	X	Z
L	Н	Н
L	L	L

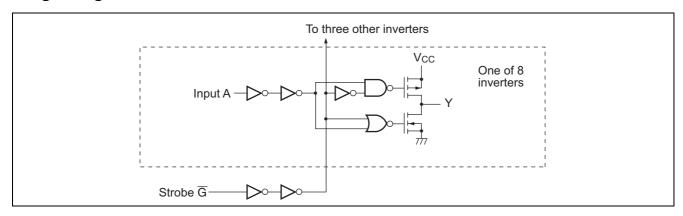
H: high level
L: low level
X: irrelevant

Z : off (high-impedance) state of a 3-state output

Pin Arrangement



Logic Diagram



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
Input / Output voltage	V _{IN} , V _{OUT}	-0.5 to V _{CC} +0.5	V
Input / Output diode current	I _{IK} , I _{OK}	±20	mA
Output current	I _O	±35	mA
V _{CC} , GND current	I _{CC} or I _{GND}	±75	mA
Power dissipation	P _T	500	mW
Storage temperature	Tstg	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{CC}	4.5 to 5.5	V	
Input / Output voltage	V _{IN} , V _{OUT}	0 to V _{CC}	V	
Operating temperature	Та	-40 to 85	°C	
Input rise / fall time*1	t _r , t _f	0 to 500	ns	V _{CC} = 4.5 V

Notes: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

Electrical Characteristics

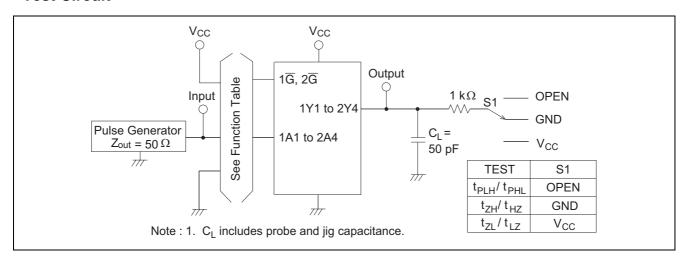
Item	Symbol	V _{CC} (V)	Ta = 25°C			Ta = -40 to+85°C		Unit	Test Conditions	
item			Min	Тур	Max	Min	Max	Oilit	rest Conditions	
Input voltage	V _{IH}	4.5 to 5.5	2.0		_	2.0	_	V		
	V_{IL}	4.5 to 5.5	_		0.8	_	0.8	>		
Output voltage	V _{OH}	4.5	4.4		_	4.4	_	V	Vin = V_{IH} or V_{IL} I_{OH} = $-20 \mu A$	
		4.5	4.18	_	_	4.13	_		$I_{OH} = -6 \text{ mA}$	
	V _{OL}	4.5	_	_	0.1	_	0.1	V	Vin = V_{IH} or V_{IL} I_{OL} = 20 μ A	
		4.5	_	_	0.26	_	0.33		$I_{OL} = 6 \text{ mA}$	
Off-state output	l _{OZ}	5.5	_	_	±0.5	_	±5.0	μΑ	$Vin = V_{IH} \text{ or } V_{IL},$	
current									$Vout = V_{CC} \text{ or GND}$	
Input current	lin	5.5	_		±0.1	_	±1.0	μΑ	Vin = V _{CC} or GND	
Quiescent current	I _{cc}	5.5	_	_	4.0	_	40	μΑ	Vin = V_{CC} or GND, lout = 0 μ	

Switching Characteristics

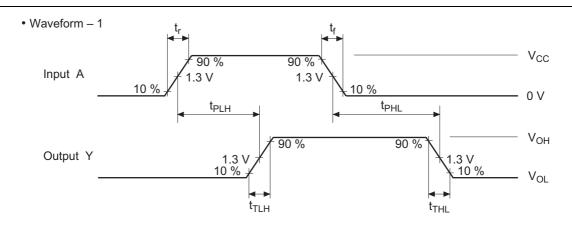
$$(C_L = 50 \text{ pF}, \text{Input } t_r = t_f = 6 \text{ ns})$$

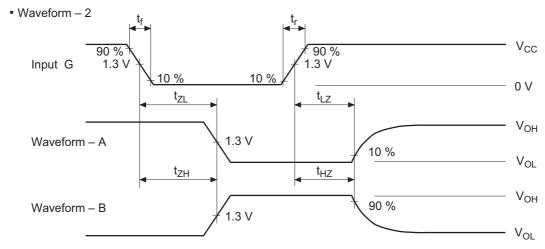
Item	Symbol	V _{cc} (V)	Ta = 25°C			Ta = -40 to +85°C		Unit	Test Conditions
item			Min	Тур	Max	Min	Max	Oilit	rest Conditions
Propagation delay time	t _{PHL}	4.5	_	11	20	_	25	ns	
	t _{PLH}	4.5		9	20	_	25		
Output enable time	t_{ZL}	4.5	_	13	30	_	38	ns	
	t _{ZH}	4.5	_	12	30	_	38		
Output disable time	t_{LZ}	4.5	_	14	30	_	38	ns	
	t _{HZ}	4.5	_	17	30	_	38		
Output rise/fall time	t _{TLH} / t _{THL}	4.5	_	4	12	_	15	ns	
Input capacitance	Cin	_	_	5	10	_	10	рF	

Test Circuit



Waveforms

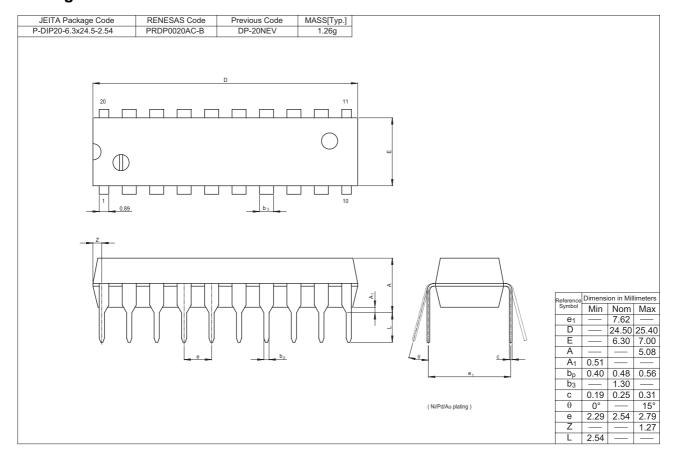


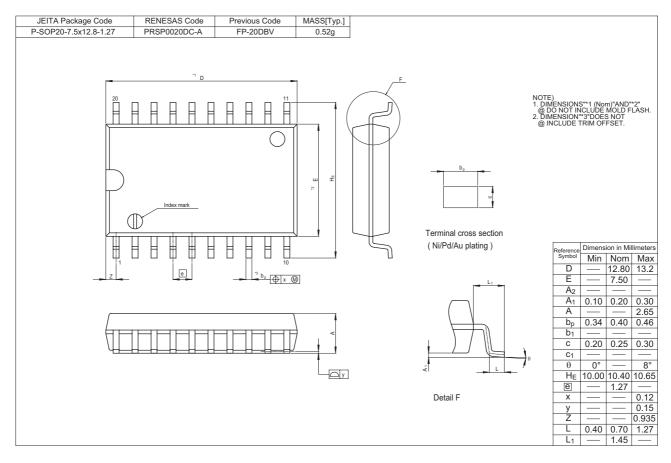


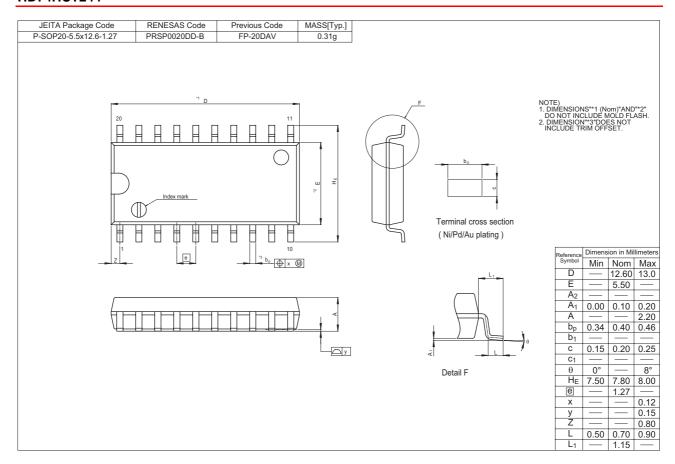
Notes : 1. Input waveform : PRR \leq 1 MHz, duty cycle 50%, $t_r \leq$ 6 ns, $t_f \leq$ 6 ns

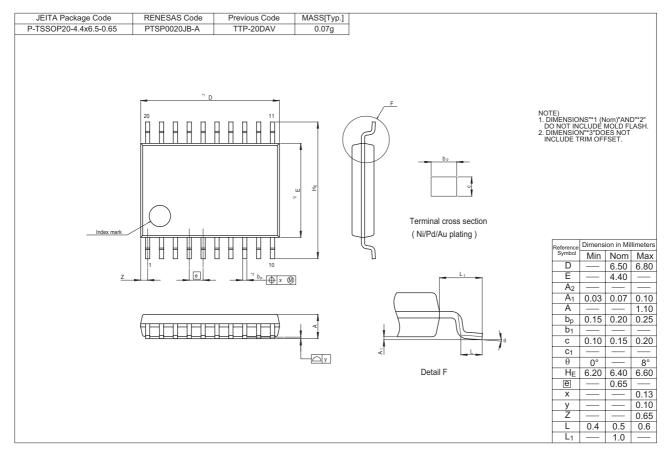
- 2. Waveform— A is for an output with internal conditions such that the output is low except when disabled by the output control.
- 3. Waveform— B is for an output with internal conditions such that the output is high except when disabled by the output control.
- 4. The output are measured one at a time with one transition per measurement.

Package Dimensions









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